

Dual Switching Diodes

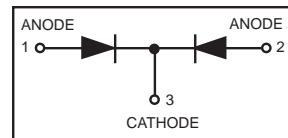
FEATURE

- Small plastic SMD package.
- For high-speed switching applications.
- Pb-Free Package is available.

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LBAV70WT1	A4	3000/Tape&Reel
LBAV70WT1G	A4 (Pb-Free)	3000/Tape&Reel

LBAV70WT1



MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Max	Unit
Reverse Voltage	V _R	70	Vdc
Forward Current	I _F	200	mAdc
Peak Forward Surge Current	I _{FM(surge)}	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board ⁽¹⁾ T _A = 25°C	P _D	200	mW
Derate above 25°C		1.6	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	0.625	°C/W
Total Device Dissipation Alumina Substrate ⁽²⁾ T _A = 25°C	P _D	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
----------------	--------	-----	-----	------

OFF CHARACTERISTICS

Reverse Breakdown Voltage (I _{BR1} = 100 μAdc)	V _(BR)	70	—	Vdc
Reverse Voltage Leakage Current (V _R = 70 Vdc)	I _{R1}	—	5.0	μAdc
(V _R = 50 Vdc)	I _{R2}	—	100	nAdc
Diode Capacitance (V _R = 0, f = 1.0 MHz)	C _D	—	1.5	pF
Forward Voltage (I _F = 1.0 mAdc)	V _F	—	715	mVdc
(I _F = 10 mAdc)		—	855	
(I _F = 50 mAdc)		—	1000	
(I _F = 150 mAdc)		—	1250	
Reverse Recovery Time (I _F = I _R = 10 mAdc, R _L = 100Ω, I _{R(REC)} = 1.0 mAdc) (Figure 1)	t _r	—	6.0	ns
Forward Recovery Voltage (I _F = 10 mAdc, t _r = 20 ns) (Figure 2)	V _{RF}	—	1.75	V

1. FR-5 = 1.0 × 0.75 × 0.062 in.

2. Alumina = 0.4 × 0.3 × 0.024 in. 99.5% alumina.

3. For each individual diode while the second diode is unbiased.

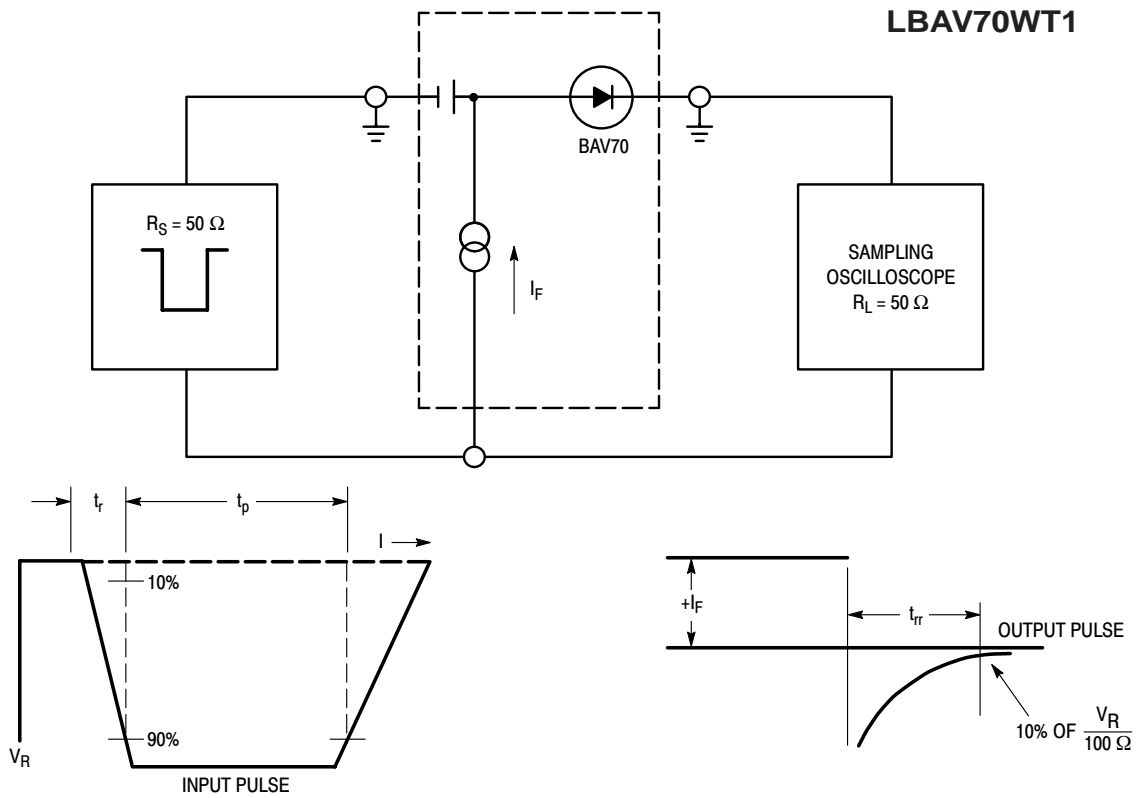


Figure 1. Recovery Time Equivalent Test Circuit

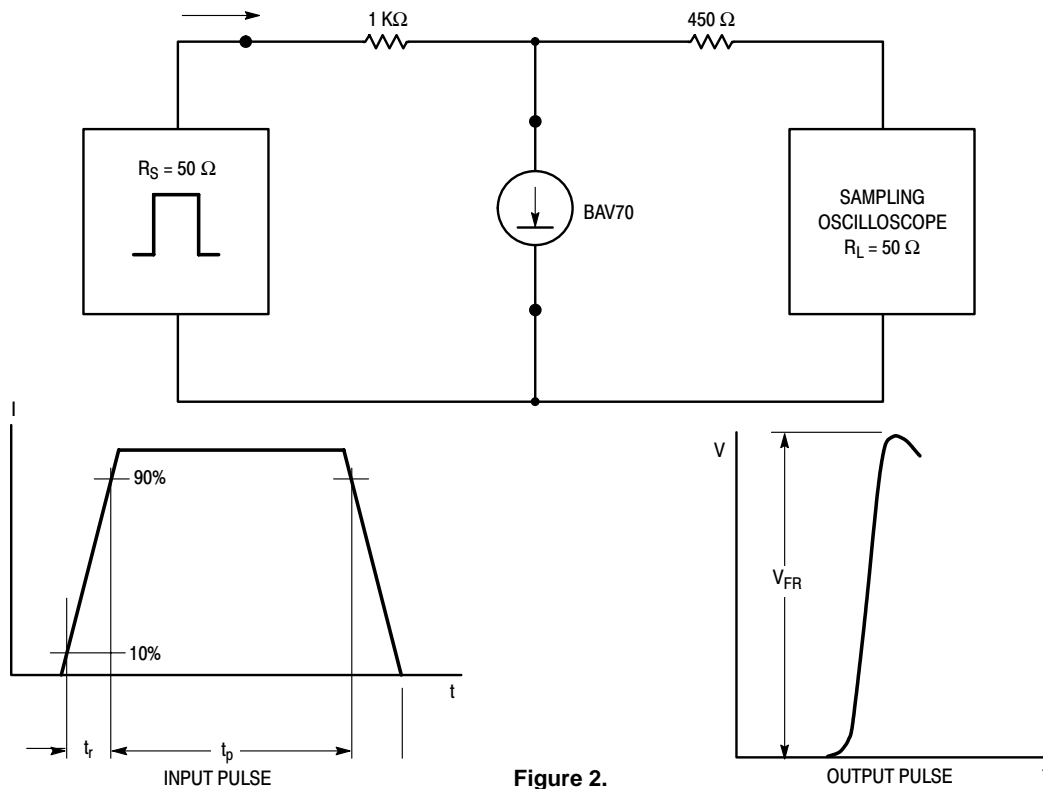
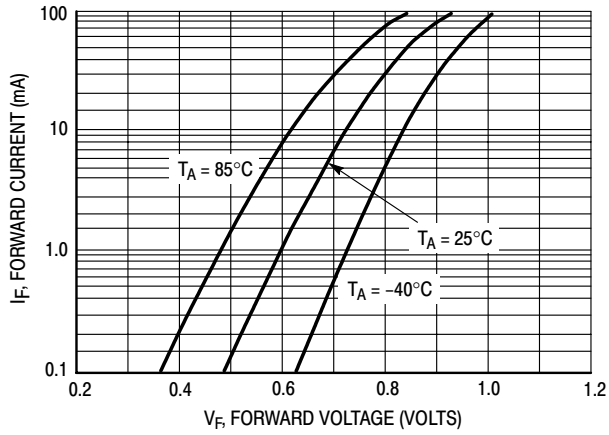
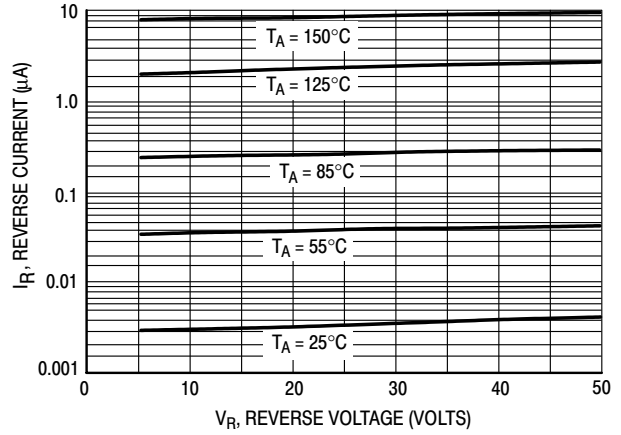
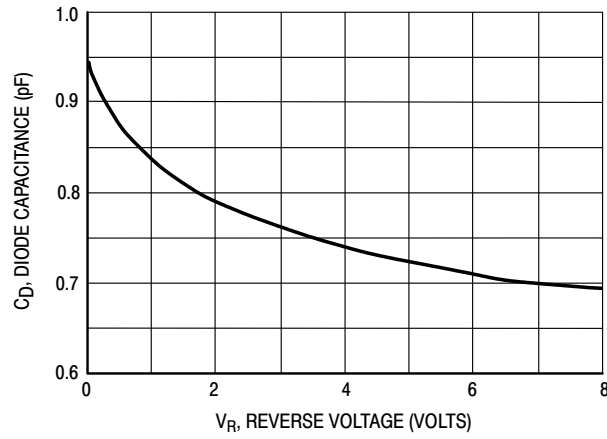


Figure 2.

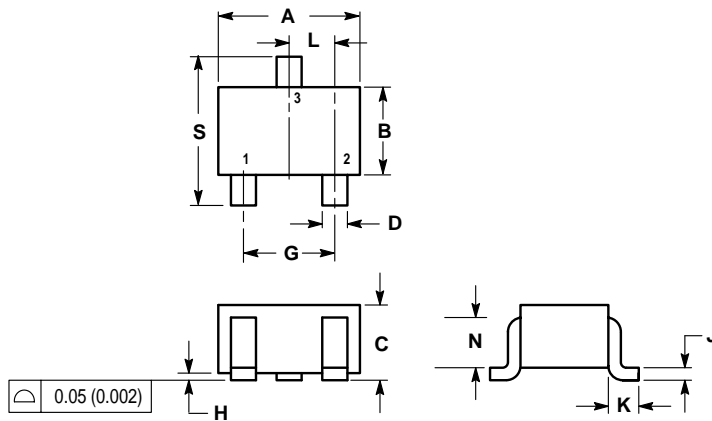
LBAV70WT1

Figure 3. Forward Voltage

Figure 4. Leakage Current

Figure 5. Capacitance

LBAV70WT1

SC-70 / SOT-323

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40

